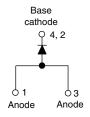


High Performance Schottky Rectifier, 3.5 A





D-PAK	(TO-252AA)
D-FAR ((10-232AA)

PRODUCT SUMMARY					
Package	D-PAK (TO-252AA)				
I _{F(AV)}	3.5 A				
V_{R}	40 V				
V _F at I _F	See Electrical table				
I _{RM}	24 mA at 125 °C				
T _J max.	150 °C				
Diode variation	Single die				
E _{AS}	8 mJ				

FEATURES

- Low forward voltage drop
- Guard ring for enhanced ruggedness and long term reliability



FREE

- Popular D-PAK outline
- · Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-30WQ04FN-M3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	3.5	Α			
V_{RRM}		40	V			
I _{FSM}	t _p = 5 μs sine	500	Α			
V _F	3 A _{pk} , T _J = 125 °C	0.49	V			
T _J		-40 to +150	°C			

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-30WQ04FN-M3	UNITS			
Maximum DC reverse voltage	V_R	40	V			
Maximum working peak reverse voltage	V_{RWM}	40	V			

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST COND	TEST CONDITIONS				
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 135 °C	3.5				
Maximum peak one cycle non-repetitive surge current. See fig. 7	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	500	Α		
		10 ms sine or 6 ms rect. pulse	V _{RRM} applied	80			
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1 A, L = 16 mH		8.0	mJ		
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		1.0	А		



ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS		
_		3 A	T _{.1} = 25 °C	0.53	V	
Maximum forward voltage drop	V _{FM} ⁽¹⁾	6 A	1j=25 C	0.67		
See fig. 1	V FM (1)	3 A	T _{.1} = 125 °C	0.49		
		6 A	1J= 125 C	0.62		
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V Detectiv	2	mA	
See fig. 2	IRM (1)	T _J = 125 °C	V _R = Rated V _R	24		
Threshold voltage	V _{F(TO)}	T - T mayimum		0.34	V	
Forward slope resistance	r _t	ıj = ıjınaxımum	$T_J = T_J$ maximum		mΩ	
Typical junction capacitance	C _T	V _R = 5 V _{DC} (test signal range	189	pF		
Typical series inductance	L _S	Measured lead to lead 5 m	5.0	nH		
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs	

Note

 $^{^{(1)}\,}$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		-40 to +150	°C		
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	4.7	°C/W		
Approximate weight			0.3	g		
Approximate weight			0.01	OZ.		
Marking device		Case style D-PAK (similar to TO-252AA)	30WC	04FN		

Note

(1)
$$\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$$
 thermal runaway condition for a diode on its own heatsink

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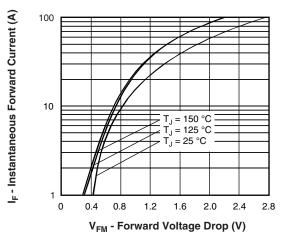


Fig. 1 - Maximum Forward Voltage Drop Characteristics

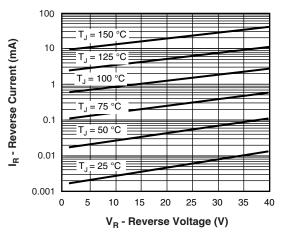


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

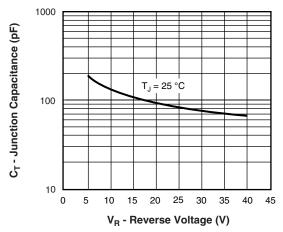


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

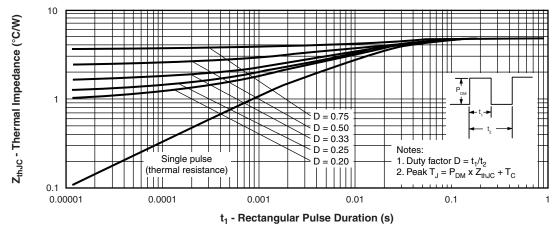


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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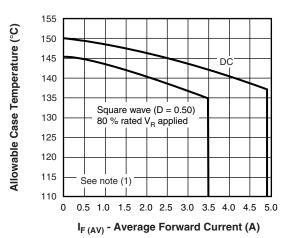


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

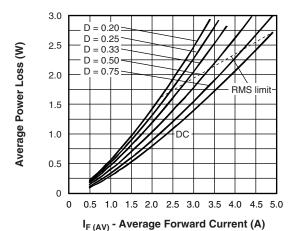


Fig. 6 - Forward Power Loss Characteristics

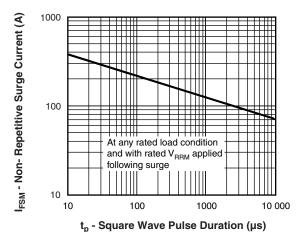


Fig. 7 - Maximum Non-Repetitive Surge Current

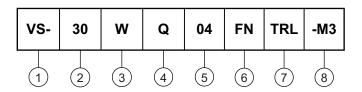
Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6);} \\ Pd_{REV} = \text{inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = 80 \text{ \% rated } V_R \\ \end{array}$



ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (3.5 A)

Package identifier:

W = D-PAK

4 - Schottky "Q" series

Voltage rating (04 = 40 V)

FN = TO-252AA (D-PAK)

7 - • None = tube

• TR = tape and reel

• TRL = tape and reel (left oriented)

• TRR = tape and reel (right oriented)

8 - Environmental digit:

-M3 = halogen-free, RoHS-compliant and terminations lead (Pb)-free

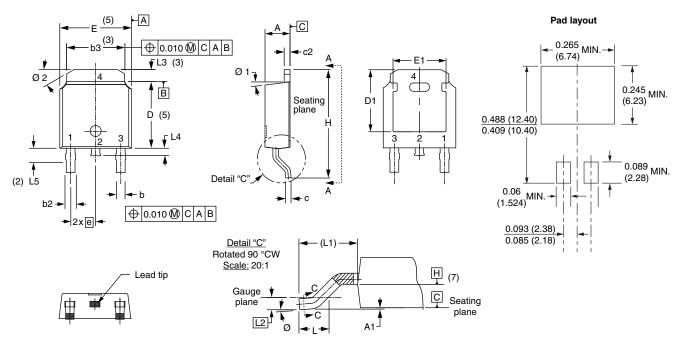
ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-30WQ04FN-M3	75	3000	Antistatic plastic tube			
VS-30WQ04FNTR-M3	2000	2000	13" diameter reel			
VS-30WQ04FNTRL-M3	3000	3000	13" diameter reel			
VS-30WQ04FNTRR-M3	3000	3000	13" diameter reel			

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95627				
Part marking information	www.vishay.com/doc?95176				
Packaging information	www.vishay.com/doc?95033				
SPICE model	www.vishay.com/doc?95288				
SFICE Model	www.vishay.com/doc?95630				



D-PAK (TO-252AA) "M"

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	MILLIMETERS INCHES		NOTES		
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	2.18	2.39	0.086	0.094		
A1	-	0.13	-	0.005		
b	0.64	0.89	0.025	0.035		
b2	0.76	1.14	0.030	0.045		
b3	4.95	5.46	0.195	0.215	3	
С	0.46	0.61	0.018	0.024		
c2	0.46	0.89	0.018	0.035		
D	5.97	6.22	0.235	0.245	5	
D1	5.21	-	0.205	-	3	
Е	6.35	6.73	0.250	0.265	5	
E1	4.32	-	0.170	-	3	

SYMBOL	MILLIMETERS		INCHES		NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
е	2.29	BSC	0.090	BSC	
Н	9.40	10.41	0.370	0.410	
L	1.40	1.78	0.055	0.070	
L1	2.74 BSC		0.108 REF.		
L2	0.51 BSC		0.020 BSC		
L3	0.89	1.27	0.035	0.050	3
L4	-	1.02	-	0.040	
L5	1.14	1.52	0.045	0.060	2
Ø	0°	10°	0°	10°	
Ø1	0°	15°	0°	15°	
Ø2	25°	35°	25°	35°	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- (5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (6) Dimension b1 and c1 applied to base metal only
- (7) Datum A and B to be determined at datum plane H
- (8) Outline conforms to JEDEC® outline TO-252AA



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